

Radiation Tolerant CAN Transceiver for Space

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- Background
- Issues
- Architecture
- Implementation
 - Transmitter
 - Overcurrent & Overvoltage Detector
- Fabrication
- Electrical Measurement
- Radiation Measurement
- Conclusion

Background



CAN bus is proposed to replace the discrete telemetry (ECSS-E-ST-50-14), PPS and on/off commands

CAN space standard (ECSS-E-ST-50-15C)

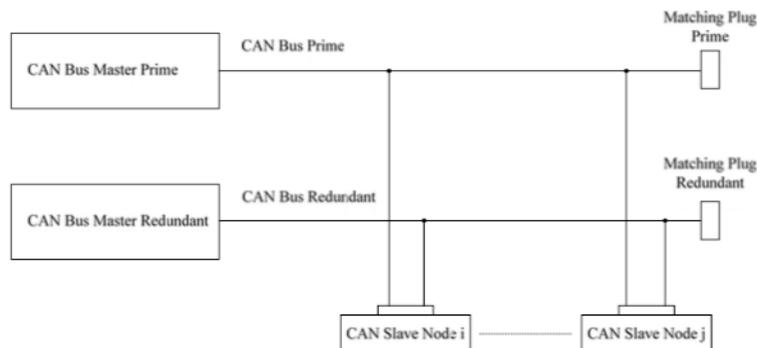
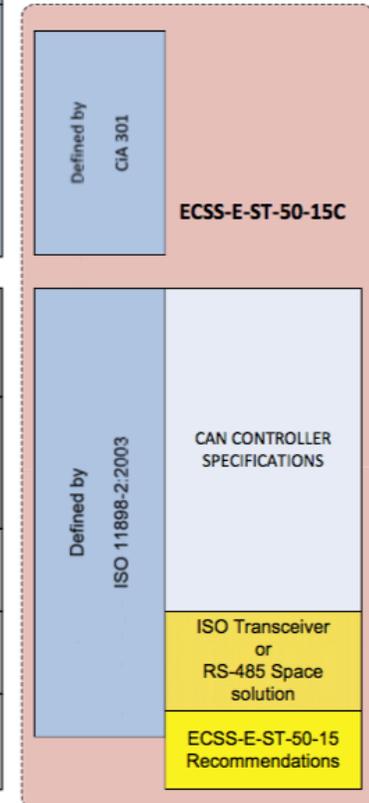
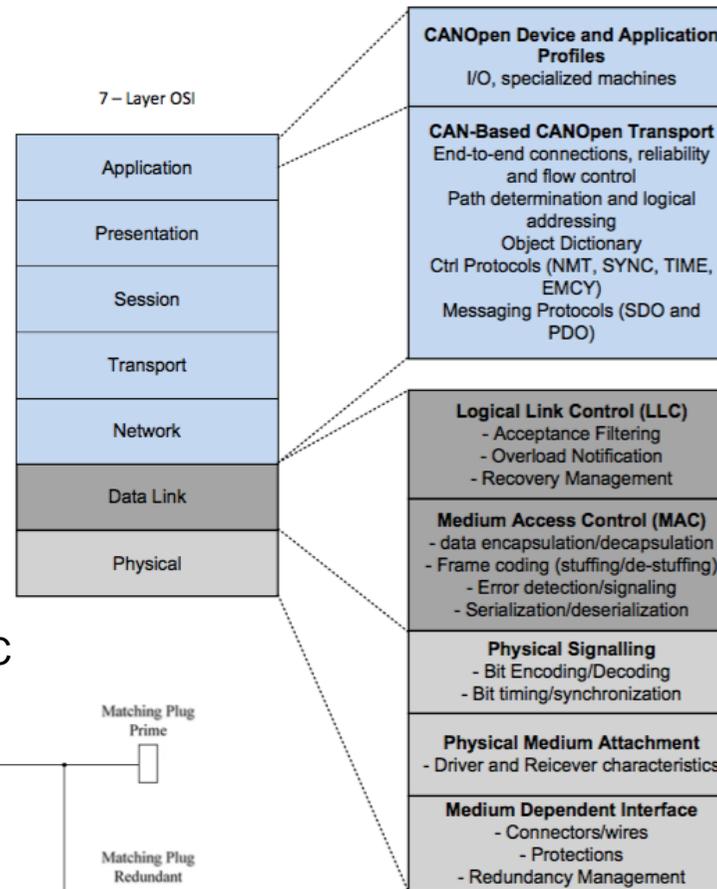
- Protocol
- Time distribution
- Redundancy
- Physical Layer

Limited number of nodes (<30)

- Separate transceiver and application IC

Large number of nodes (>100)

- Integrated transceiver and application IC



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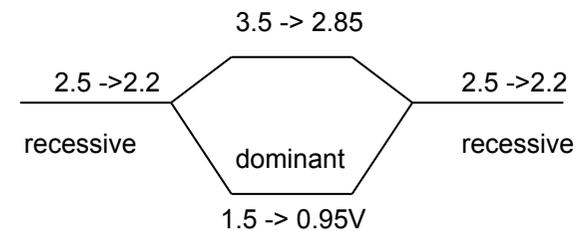
Space engineering
CANBus extension protocol

SpaceDoc-1001

Issues

Integration of the CAN Transceiver and Application on a single IC causes issues

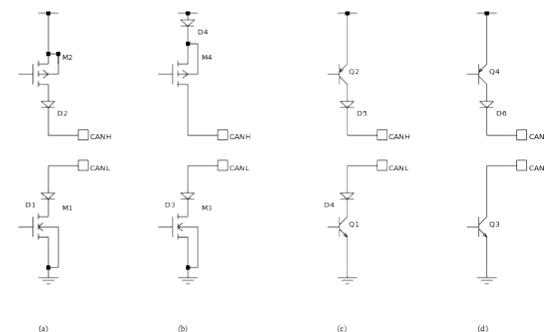
- Application supply voltage and technology is limited to 3.3V supply
- CAN dominant state differential voltage is $>1.5V$
- CAN port voltage tolerance from $-3V$ to $16V$
- CAN bus common mode range is $-2V$ to $7V$



Not all IC technologies combine

- Radiation tolerance
- High current density diodes
- High voltage transistors

Require a different approach



Conventional CAN driver output stages that prevent reverse bias leakage

Implementation - Transmitter

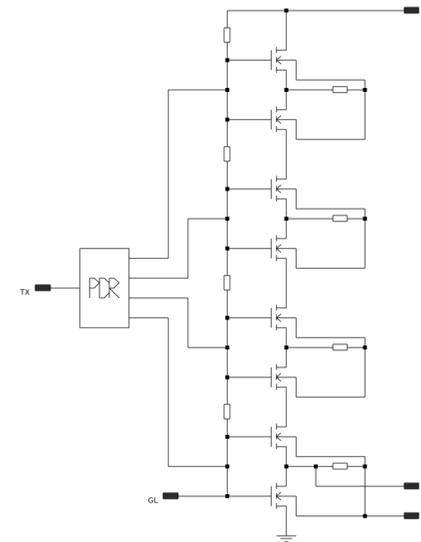
The high-voltage tolerance is realised by stacking the MOS transistors.

- In the recessive state the resistive voltage dividers ensure that the correct voltage drop occurs across the terminals of the MOS transistor
- In the dominant state the Pre-Driver (PDR) ensure that all the gates are pulled high for maximum conduction.

The reverse leakage is prevented by joining the wells between two MOS transistors

Over current protection should be realised by measuring the current through the first MOS transistor for the forward and reverse direction

Over voltage protection should ensure that the driver stays in recessive state if the port voltage is larger than 16V

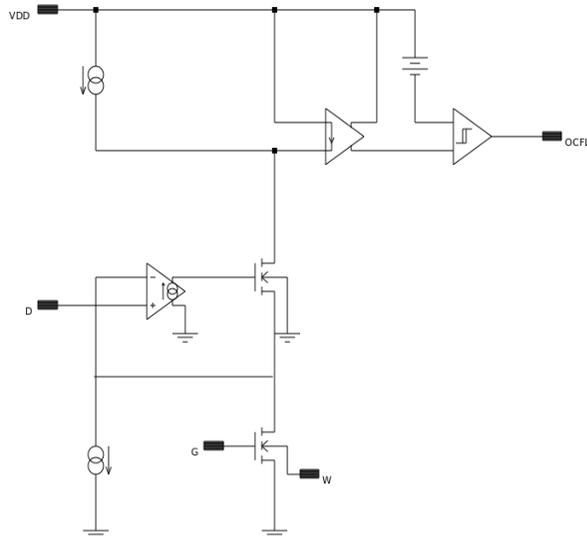


CAN L Port Driver Circuit

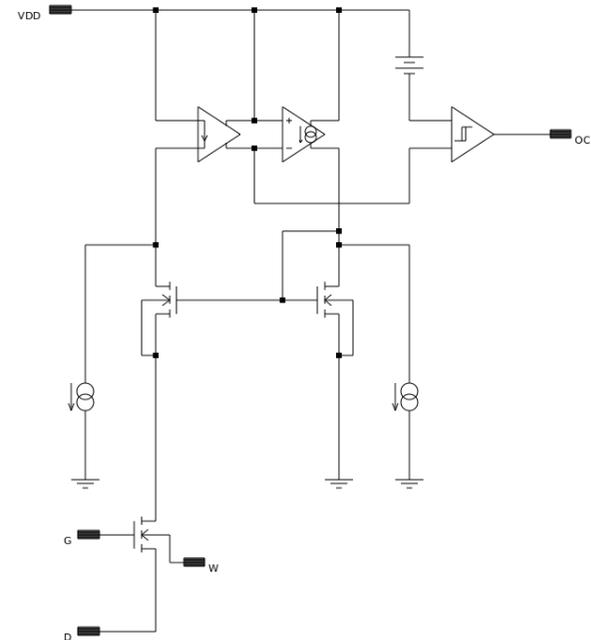
Implementation - Detector



CAN L port forward over-current detection



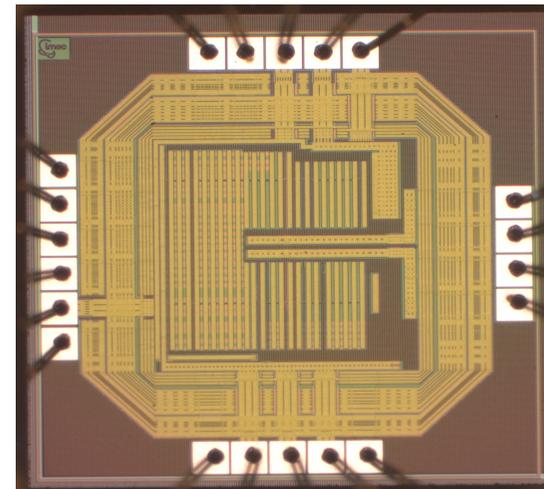
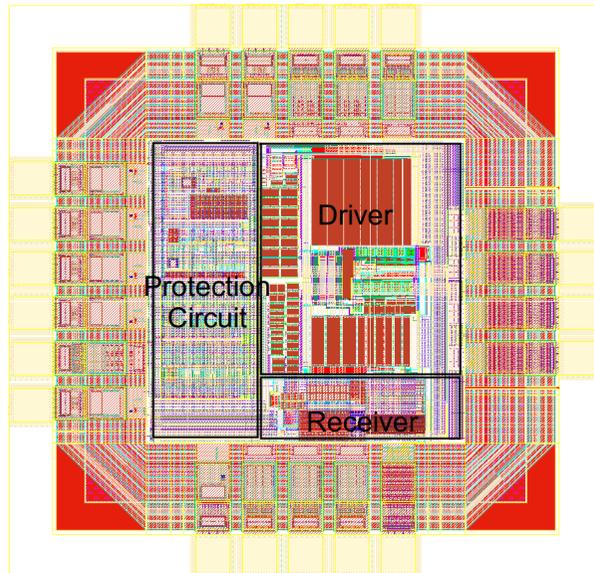
CAN L port reverse over-current detection



Fabrication

CAN transceiver has been manufactured in the DARE180U technology

Die packaged in a SOIC 20 pin package

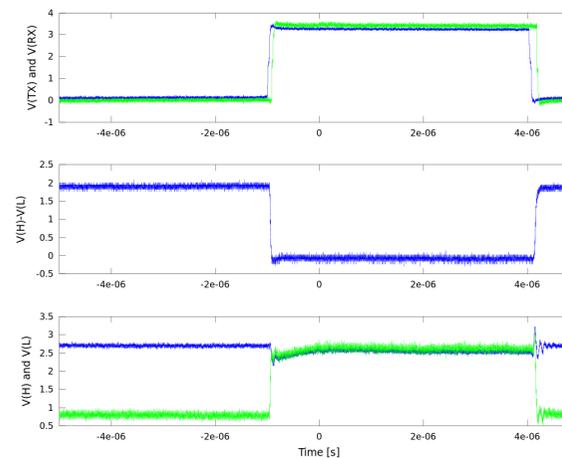


Receiver

Description	Symbol	Unit	Min	Typ	Max
RX Threshold: D->R	$V_{diff,TH,RD}$	V	557	684	782
RX Threshold: R->D	$V_{diff,TH,DR}$	V	630	750	843
RX Hysteresis	V_{HYS}	mV	48	66	88

Transmitter

Description	Symbol	Unit	Min	Typ	Max
CANH Dominant	$V_{CANH,D}$	V	2.340	2.668	3.012
CAN L Dominant	$V_{CANL,R}$	V	0.587	0.693	0.879
CANH Recessive	$V_{CANH,D}$	V	1.991	2.196	2.404
CANL Recessive	$V_{CANL,R}$	V	1.989	2.195	2.403
Dominant Differential	$V_{diff,D}$	V	1.538	1.973	2.379
Recessive Differential	$V_{diff,R}$	V	0.001	0.001	0.001



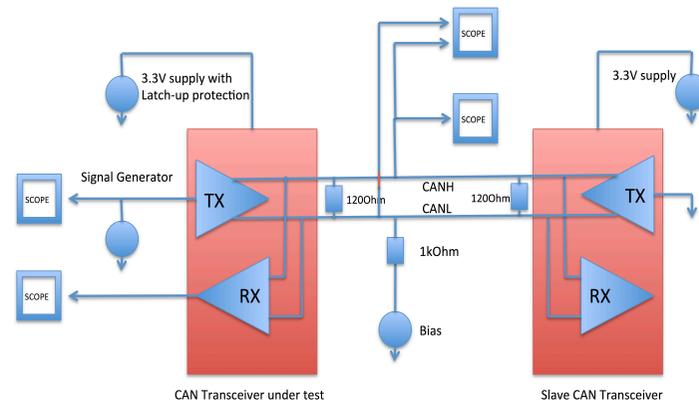
Transceiver in loopback configuration

- TX and RX signals
- CAN differential signal
- CAN H and L signals

Transceiver

Description	Symbol	Unit	Min	Typ	Max
Current Recessive	I_R	mA	2	3	4
Current Dominant	I_D	mA	29	37	45
Input resistance	R_{in}	k Ω		22	
Input resistance matching	M_{in}	%			1
Differential input resistance	R_{diff}	Ω		22	
Input capacitance CANH	$C_{in,CANH}$	pF		3.5	
Input capacitance CANL	$C_{in,CANL}$	pF		3.5	
Differential input capacitance	C_{diff}	pF		3.8	
Propagation Delay CMOS -> CAN: R -> D	$t_{TX,RD}$	ns	70	90	115
Propagation Delay CMOS -> CAN: D -> R	$t_{TX,DR}$	ns	30	35	40
Propagation Delay CAN -> CMOS: R -> D	$t_{RX,RD}$	ns	20	25	30
Propagation Delay CAN -> CMOS: D -> R	$t_{RX,DR}$	ns	25	30	45
Propagation Delay Loop R -> D	$t_{LOOP,RD}$	ns	100	120	140
Propagation Delay Loop D -> R	$t_{LOOP,DR}$	ns	60	65	75

CAN Transceiver in loopback configuration



LET [MeVcm ² /mg]	RX+TX cross-section [cm ²]
6.4	4.5 x10 ⁻⁷
24.0	1.5 x10 ⁻⁷
49.0	2.8 x10 ⁻⁷
72.1	3.3 x10 ⁻⁷

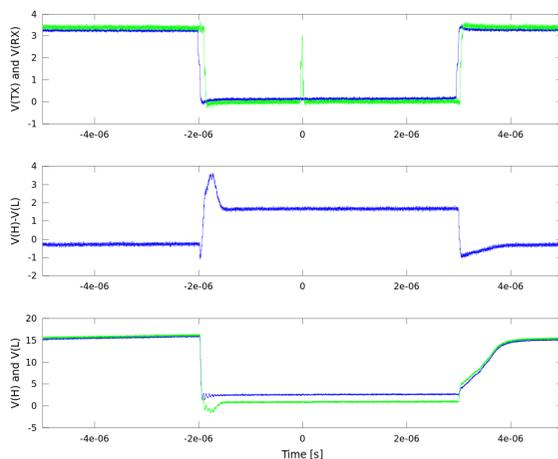
CAN Transceiver Cross-section

Radiation Measurements

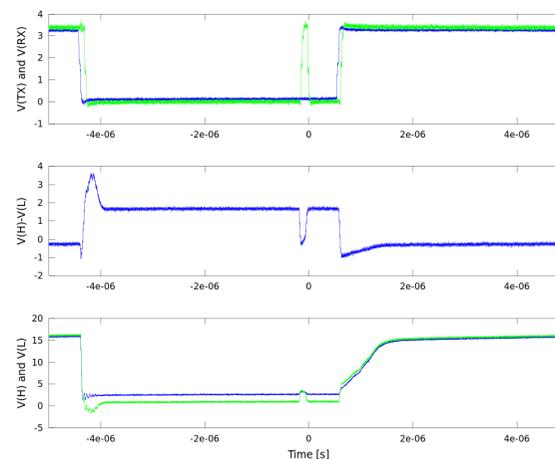


CAN Transceiver in loopback configuration with common-mode bias

Ions	Angle [deg]	LET [MeVcm ² /mg]	Fluence [cm ⁻²]	Temp. [C]	Bias [V]
Xe-136	0	61.02	1 x10 ⁷	25	2.0
Xe-136	0	61.02	5 x10 ⁹	25	5.5
Xe-136	0	61.02	5 x10 ⁹	25	7
Xe-136	0	61.02	5 x10 ⁹	25	10
Xe-136	0	61.02	1 x10 ⁷	25	16.0
Xe-136	0	61.02	1 x10 ⁷	25	22.5



SET recorded in RX circuit



SET recorded in TX circuit

TX and RX signals

CAN Differential bus signal

CAN H and L bus signals

Conclusion



CAN Transceiver has been realised

- compliant to CAN standard
- radiation Tolerant

Possibly world first CAN transceiver realisation in low-voltage 3.3V digital CMOS process
Two patents have been filed that cover the CAN transistor architecture and driver

CAN transceiver implementation does not include

- ESD protection
- Improved RX section to reduce SET cross-section

Voltage tolerance of 3.3V DARE180U CMOS technology extended to 16V

Thank you



Any Questions?